## NSN 5961-00-840-5385

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-840-5385 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-41 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 400.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.50 amperes source cutoff current and 1.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli